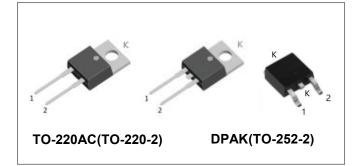






S4D02120A S4D02120E 1200V SIC POWER SCHOTTKY RECTIFIERS



Circuit Diagram



Description

This 1200V 2A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S4D02120A/S4D02120E are ideal for energy sensitive, high frequency applications in challenging environments.

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

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Maximum Ratings				
Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	1200	V
Average Rectified Forward Current	I _{F (AV)1}	Tc=25°C	9	А
Average Rectilieu i ol ward Current	I _{F (AV)2}	Tc=160°C	2	A
Peak One Cycle Non-Repetitive Surge	I _{FSM1}	10ms, Half Sine pulse, Tc =25°C	27	А
Current	I _{FSM2}	10ms, Half Sine pulse, Tc =110°C	25	А
	I_{FRM1}	10ms, Half Sine pulse , Tc =25°C	16	A
Repetitive Peak Forward Surge Current	I_{FRM2}	10ms, Half Sine pulse , Tc =110°C	14	A
Non-Repetitive Peak Forward Surge	I _{F,Max1}	10µs. Pulse, Tc=25°C	200	А
Current	I _{F,Max2}	10µs. Pulse, Tc=110°C	160	А
	P _{tot1}	Tc =25℃	60	W
Power Dissipation	P _{tot2}	Tc=110°C	26	W

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S4D02120A

Electrical Characteristics:					
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 2A, Pulse, T _J = 25 °C	1.4	1.8	V
	V _{F2}	@ 2A, Pulse, T _J = 175 °C	2.0	2.5	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	1	10	uA
	I _{R2}	$@V_R = rated V_R$ T _J = 175 °C	2	40	uA
Junction Capacitance	Ст	VR=0V, Tj=25℃,f=1MHz	160	-	pF
Reverse Recovery Charge	Qc	I _F = 2A, di/dt = 200A/µs VR = 800 V, TJ =25°C	12.33	-	nC
Capacitance Stored Energy	Ec	V _R = 800 V, T _J =25°C	6.33	-	μJ

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	S4D02120A	S4D02120E	Units
Junction Temperature	TJ	-55 to +175		°C
Storage Temperature	T _{stg}	-55 to +175		°C
Typical Thermal Resistance Junction to Case	R _{qJC}	2.4	2.5	°C/W

Ordering Information

Device	Package	Shipping
S4D02120A	TO-220AC(TO-220-2)	50pcs / tube
S4D02120E	DPAK(TO-252-2)	2500pcs / reel
S4D02120ETR	DPAK(TO-252-2)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.







Ratings and Characteristics Curves

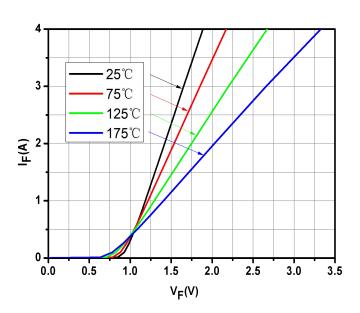


Fig.1-Typical Forward Voltage Characteristics

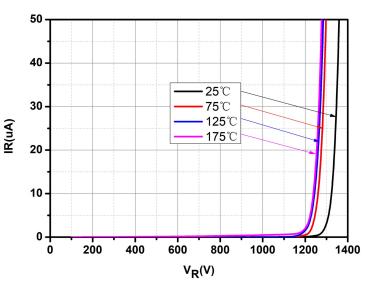


Fig.2-Typical Reverse Characteristics

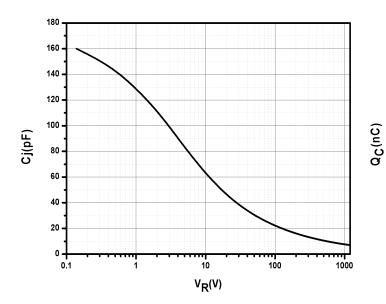


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage







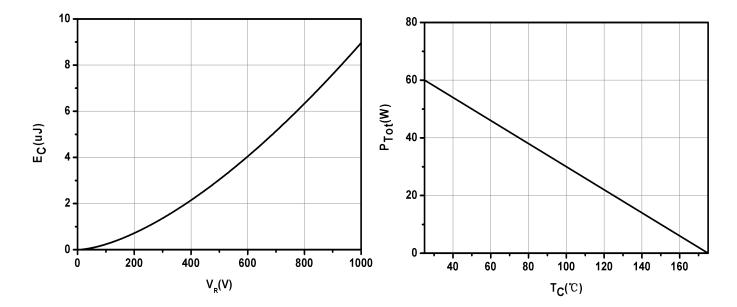


Fig.5-Capacitance Stored Energy

Fig.6-Power Derating

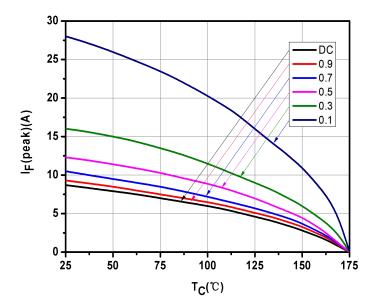


Fig.7-Current Derating

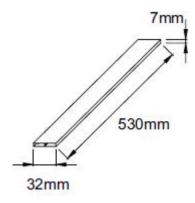


Marking Diagram

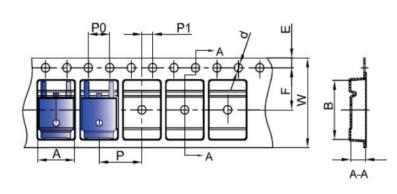
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Tube Specification(TO-220-2)



Carrier Tape & Reel Specification DPAK(TO-252-2)



SYMBOL	Millimet	ters
STMBOL	Min.	Max.
A	6.80	7.00
В	10.40	10.60
С	2.60	2.80
d	Φ1.45	Ф1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
Р	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

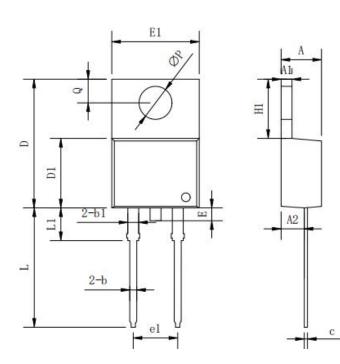


Data Sheet N2369, REV. D

S4D02120A S4D02120E

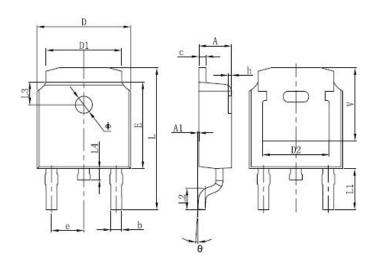


Mechanical Dimensions TO-220AC(TO-220-2)



Symbol	Dimensions in millimeters			
-	Min.	Typical	Max.	
A	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
с	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	-	-	1.78	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ΦΡ	-	3.56	-	
Q	2.54	-	3.43	

Mechanical Dimensions DPAK(TO-252-2)



SYMBOL	Dimensions in millimeters			
	Min.	Тур.	Max.	
A	2.18	-	2.39	
A1	-	-	0.13	
b	0.64	-	0.89	
с	0.46	-	0.89	
D	6.35	-	6.73	
D1	4.95	-	5.46	
D2	4.32	-	-	
E	5.97	6.1	6.22	
е		2.29BSC		
L	9.4	-	10.41	
L1	2.90 REF.			
L2	1.4	1.52	1.78	
L3	1.60 REF.			
L4	_	-	1.02	
Φ	1.1	-	1.3	
Θ	0°	-	10°	
V	5.21	-	-	







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